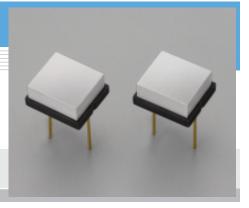
PHOTODIODE

Si photodiode \$8559

Detector for X-ray monitor

Features

- Si photodiode coupled to low cost CsI scintillator
- Ideal for detection of X-ray energy below 100 keV



Applications

- X-ray detection
- X-ray monitors

■ Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Value	Unit
Reverse voltage	VR Max.	5	V
Operating temperature	Topr	-10 to +60	С°
Storage temperature	Tstg	-20 to +70	°C

■ Electrical and optical characteristics (without scintillator, Ta=25 °C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Spectral response range	λ		-	190 to 1000	-	nm
Peak sensitivity wavelength	λρ			720	-	nm
Photo sensitivity	S	λ=500 nm	-	0.26	-	A/W
Dark current	lo	Vr=10 mV	-	2	50	pА
Terminal capacitance	Ct	VR=0 V, f=10 kHz	-	950	-	pF

■ X-ray sensitivity (reference value, tube current: 1.0 mA, aluminum filter: t=6 mm, distance=830 mm)

X-ray tube voltage	Тур.	Unit
120 kV	52	nA

Note) Depends on equipment and measurement conditions.

Handling precautions

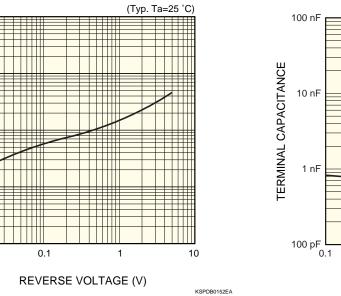
Avoid storing or using S8559 at high humidity because CsI scintillator has deliquescence.

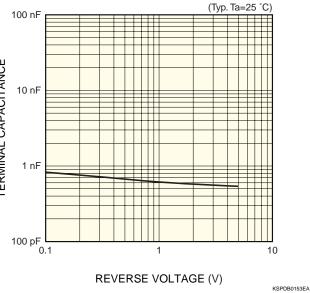


HAMAMATSU

Si photodiode S8559

Terminal capacitance vs. reverse voltage





Dimensional outline (unit: mm)

Dark current vs. reverse voltage

1 nA

100 pA

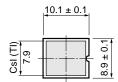
10 pA

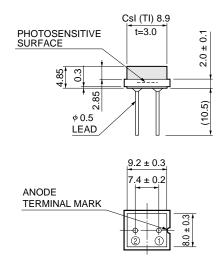
1 pA

100 fA

0.01

DARK CURRENT





② ⊶ ◄ • ①

KSPDA0145EA

Information described in this material is current as of June, 2011. Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept Absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.



HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184, www.hamamatsu.com

U.S.A.: Hamanatsu Corporation: 360 Foothill Road, PO.Box 6910, Bridgewater, N.J. 08807-0910, U.S.A.: Telephone: (1) 908-231-218 Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-0, Fax: (49) 8152-265-8 France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 10, Fax: 33-(1) 69 53 71 10 United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777 North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171 41 Solna, Sweden, Telephone: (46) 8-509-031-01 Italy: Hamamatsu Photonics Italia S.R.L.: Strada della Moia, 1 int. 6, 20020 Arese, (Milano), Italy, Telephone: (39) 02-935-81-733, Fax: (39) 02-935-81-741